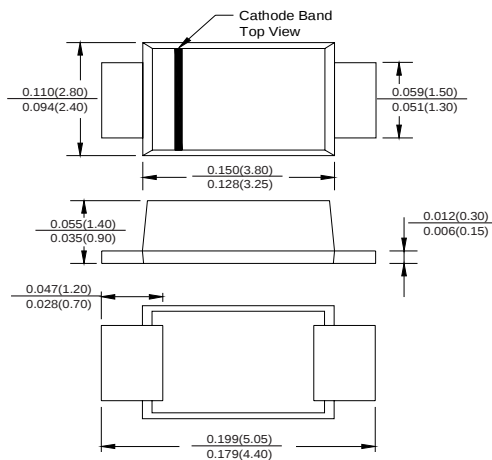


FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- For surface mount applications
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- Low profile package
- built-in strain relief ,ideal for automated placement
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



SMAF



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case : S M A F
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 27mg (0.00086oz)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%.)

		Symbols	SS 32L	SS 33L	SS 34L	SS 35L	SS 36L	SS 38L	SS 310L	SS 315L	SS 320L	Volts
Maximum repetitive peak reverse voltage		VRRM	20	30	40	50	60	80	100	150	200	Volts
Maximum RMS voltage		VRMS	14	21	28	35	42	57	71	105	140	Volts
Maximum DC blocking voltage		VDC	20	30	40	50	60	80	100	150	200	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length (See Fig.1)		l(AV)	3.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		lFSM	80.0									Amps
Maximum instantaneous forward voltage at 3.0 A(Note 1)		VF	0.45			0.52		0.68		0.80	0.85	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	Ta=25°C	IR	0.2									mA
	Ta=100°C		20			10						
Typical junction capacitance(Note 3)		CJ	250			160						pF
Typical thermal resistance (Note 2)		RθJA RθJL	55.0 17.0									°C/W
Operating junction temperature range		TJ	-65 to+150									°C
Storage temperature range		TSTG	-65 to+150									°C

Notes: 1. Pulse test: 300 μs pulse width, 1% duty cycle

2. P.C.B. mounted 0.55 X 0.55"(14 X 14mm) copper pad areas

3. Measured at 1MHz and reverse voltage of 4.0volts

FIG.1-FORWARD CURRENT DERATING CURVE

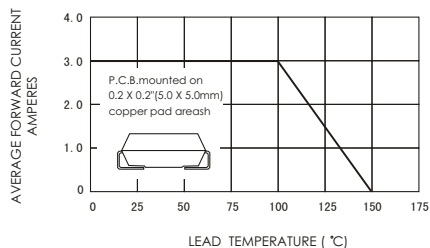


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

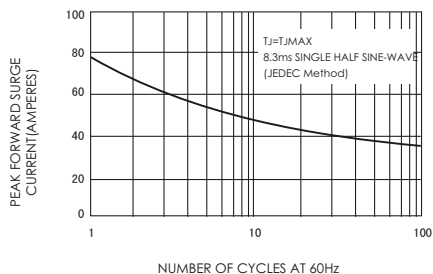


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

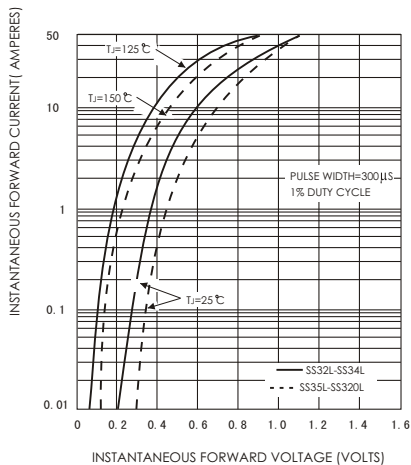


FIG.4-TYPICAL REVERSE CHARACTERISTICS

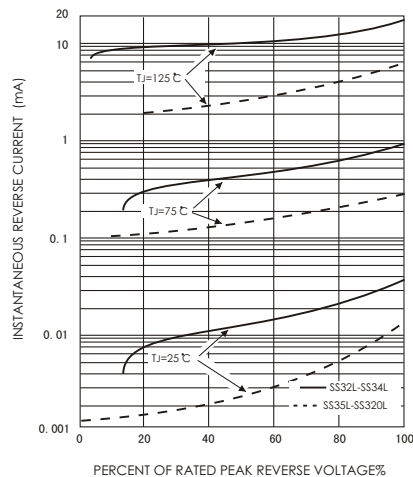


FIG.5-TYPICAL JUNCTION CAPACITANCE

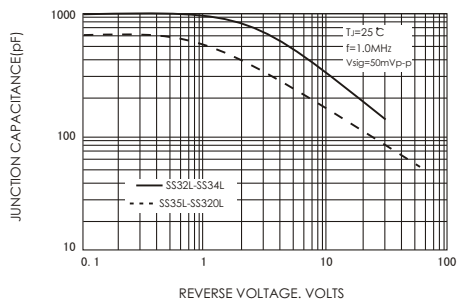


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

